



MMC 4051 MMC 4052 MMC 4053

ANALOG MULTIPLEXERS-DEMULTIPLEXERS:

4051 SINGLE 8-CHANNEL

4052 DIFFERENTIAL 4-CHANNEL

4053 TRIPLE 2-CHANNEL

GENERAL DESCRIPTION

The MMC 4051, MMC 4052 and MMC 4053 are monolithic integrated circuits, available in 16-lead dual-in-line plastic or ceramic package. MMC 4051, MMC 4052 and MMC 4053 analog multiplexers/demultiplexers are digitally controlled analog switches having low ON impedance and very low OFF leakage current. These multiplexer circuits dissipate extremely low quiescent power over the full V_{DD} - V_{SS} and V_{DD} - V_{EE} supply-voltage ranges, independent of the logic state of the control signals. When a-logic "1" is present at the inhibit input terminal all channel are off. The MMC 4051 is a single 8-channel multiplexer having three binary control inputs, A, B and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output. The MMC 4052 is a differential 4-channel multiplexer having two binary control inputs, A and B, and an inhibit input. The two binary input signals select 1 of 4 pairs of channels to be turned on and connect the analog inputs to the outputs.

The MMC 4053 is a triple 2-channel multiplexer having three separate digital control inputs, A, B, and C and an inhibit input. Each control input selects one of a pair of channels which are connected in a singlepole double-throw configuration.

FEATURES

- Low „ON“ resistance: 125 ohm (typ.) over 15 Vp.p. signal-input range for $V_{DD}-V_{EE} = 15$ V
- High „OFF“ resistance: channel leakage ± 100 pA (typ.) $V_{DD}-V_{EE} = 18$ V
- Binary address decoding on chip
- Very low quiescent power dissipation under all digital control input and supply conditions: 0.2/ μ W (typ.), $V_{DD}-V_{SS} = V_{DD}-V_{EE} = 10$ V
- Matched switch characteristics: $R_{ON} = 5$ ohm (typ.) for $V_{DD}-V_{EE} = 15$ V
- Wide range of digital and analog signal levels: digital 3 to 20 V, analog to 20 Vp.p.

ABSOLUTE MAXIMUM RATINGS

V_{DD}^*	Supply voltage: G and H types E and F types	-0.5 to	20	V
V_i	Input voltage	-0.5 to	18	V
$I_{P_{tot}}$	DC input current (any one input)	-0.5 to	$V_{DD} + 0.5$	V
	Total power dissipation (per package)		± 10	mA
	Dissipation per output transistor for $T_A =$ full package-temperature range		200	mW
T_A	Operating temperature : G and H types E and F types		100	mW
T_{Stg}	Storage temperature	-55 to	125	°C
		-40 to	85	°C
		-65 to	150	°C

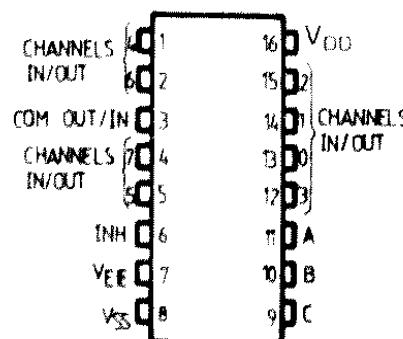
* All voltage values are referred to V_{SS} pin voltage

RECOMMENDED OPERATING CONDITIONS

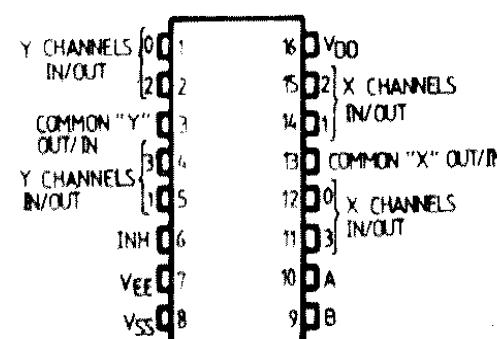
V_{DD}^*	Supply voltage: G and H types E and F types	3 to	18	V
V_i	Input voltage	3 to	15	V
T_A	Operating temperature : G and H types E and F types	0 to	V_{DD}	V
		-55 to	125	°C
		-40 to	85	°C

CONNECTION DIAGRAMS

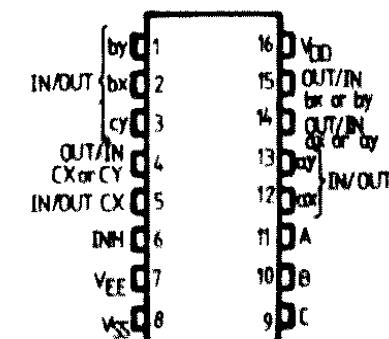
MMC 4051



MMC 4052



MMC 4053



MMC 4051 MMC 4052 MMC 4053**STATIC ELECTRICAL CHARACTERISTICS**

(over recommended operating conditions)

PARAMETER	V _{IS} - (V)	TEST CONDITIONS				VALUES						UNIT	
		V _{EE} (V)	V _{SS} (V)	V _{DD} (V)	T [*] LOW		25°C			T [*] HIGH			
					min.	max.	min.	typ.	max.	min.	max.		
I _L quiescent device current	G, H types				5		5		0.04	5		150	
					10		10		0.04	10		300	
					15		20		0.04	20		600	
					20		100		0.08	100		3000	
	E, F types				5		20		0.04	20		150	
					10		40		0.04	40		300	
					15		80		0.04	80		600	

Switch

ON-resistance	G, H types	0≤V _I ≤V _{DD}	0	0	5 10 15	880 310 220		470 180 125	1050 400 280		1200 580 400	Ω
ΔON-resistance (between any 2 channels)	E, F types	0≤V _I ≤V _{DD}	0	0	5 10 15	880 330 230		470 180 125	1050 400 280		1200 520 360	
OFF (•) channel	Any channel OFF	G, H types	0	0	18	100		±0.1	100		1000	nA
leakage current	All channels OFF (common OUT/IN)	G, H types	0	0	18	100		±0.1	100		1000	nA
	Any channel OFF	E, F types	0	0	15	300		±0.1	300		1000	nA
	All channels OFF (common OUT/IN)	E, F types	0	0	15	300		±0.1	300		1000	nA
C-capaci- tance	Input							5				
	Output 4051							30				
	Output 4052							18				
	Output 4053							9				
	Feedthrough							0.2				

Control (Address or Inhibit)

V _{IL} Input low voltage	= V _{DD} thru 1KΩ	V _{EE} = V _{SS} R _I = 1KΩ to V _{SS}	5 10 15		1.5 .3 4			1.5 3 4		1.5 3 4		V
V _{IH} Input high voltage		I _S > 2μA (on all OFF channels)	5 10 15	3.5 7 11		3.5 7 11			3.5 7 11			V

MMC 4051 MMC 4052 MMC 4053**STATIC ELECTRICAL CHARACTERISTICS**

(over recommended operating conditions)

PARAMETER		TEST CONDITIONS				VALUES						UNIT
		V _{IS} (V)	V _{EE} (V)	V _{SS} (V)	V _{DD} (V)	T _{Low}		25°C			T _{High}	
						min.	max.	min.	typ.	max.	min.	max.
I _H , I _L Input leakage current	G, H types	V _I = 0/18 V		18			±0.1		±10 ⁻³	±0.1		±1
	E, F types	V _I = 0/15 V		15			±0.3		±10 ⁻³	±0.3		±1
C _I Input capacitance		Any address or inhibit input							5	7.5		

(o) Determined by minimum feasible leakage measurement for automatic testing

(±%) T_{Low} = -55°C for G, H device; -40°C for E, F device.T_{High} = +125°C for G, H device; +85°C for E, F device.**DYNAMIC ELECTRICAL CHARACTERISTICS**(T_A = 25°C, C_L = 50 pF, all input square wave rise and fall time = 20 ns)

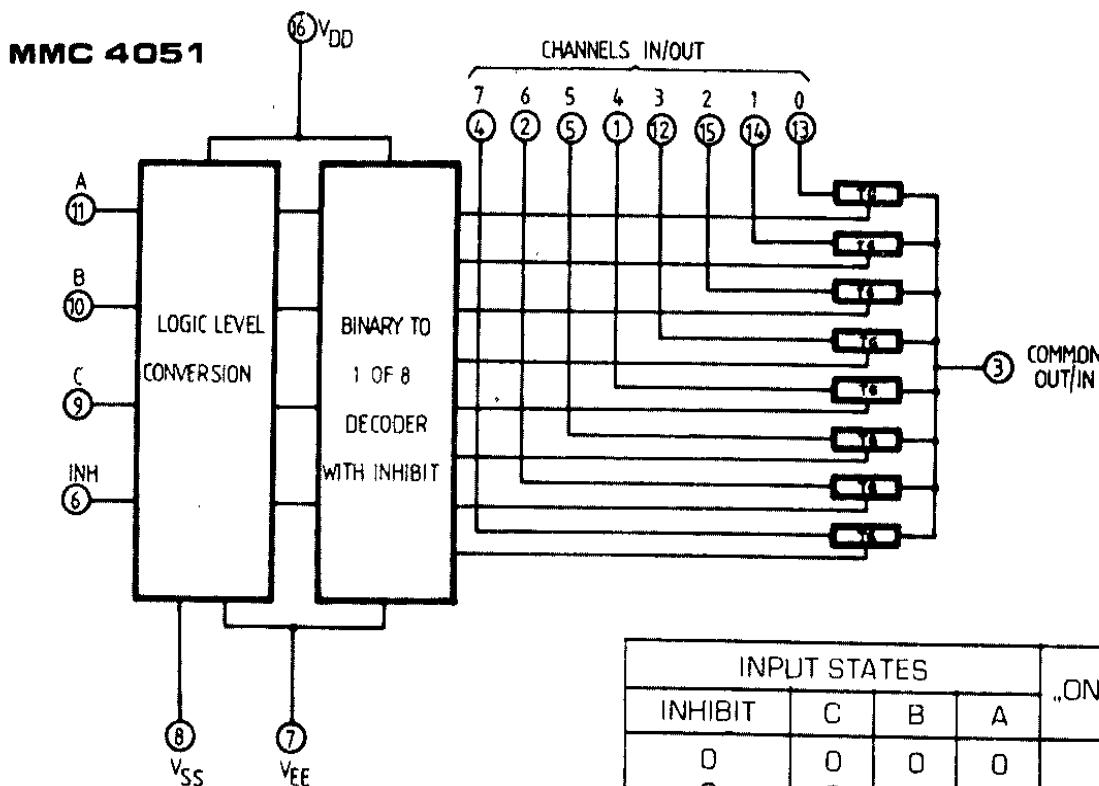
PARAMETER		TEST CONDITIONS						VALUES			UNIT
		V _{EE} (V)	R _L (KΩ)	f _i (KHz)	V _{IS} (V)	V _{SS} (V)	V _{DD} (V)	typ.	max.		
Switch											
t _{pd} Propagation delay time (Signal Input to output)		200		10 V		5				30 15 11	30 60 20
Frequency response channel „ON” (Sine wave Input) at	=V _{SS}	1		5(°)		10	V _O at common OUT/IN		4053 4052 4051	30 25 20	MHz
							V _O at any channel			60	
Feedthrough (all channels OFF) at 20 Log V _O / V ₁ = -3 dB	=V _{SS}	1		5(°)		10	V _O at common OUT/IN		4053 4052 4051	8 10 12	MHz
							V _O at any channel			8	
Frequency signal crosstalk at 20 Log V _O / V ₁ = -40 dB	=V _{SS}	1		5(°)		10	Between any 2 channels			3	MHz
							Measured on common			6	
Sine wave distortion f _{IS} = 1 KHz sine wave	=V _{SS}	10	1	20(°)		5	Measured on any channel			10	MHz
							Between any 2 sections 4053 only		In pin 2 out pin 14	2.5	
							In pin 15 out pin 14			6	
									0.3 0.2 0.12		%

MMC 4051 MMC 4052 MMC 4053

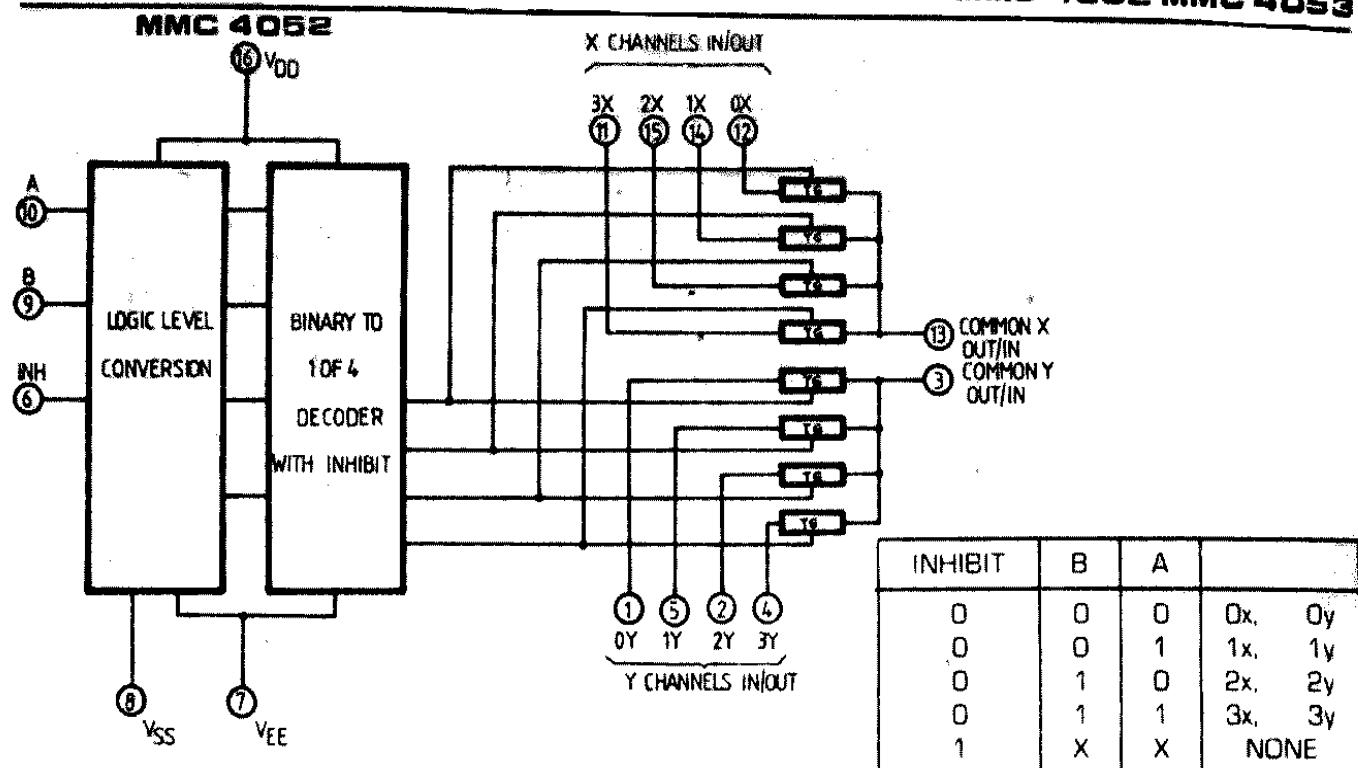
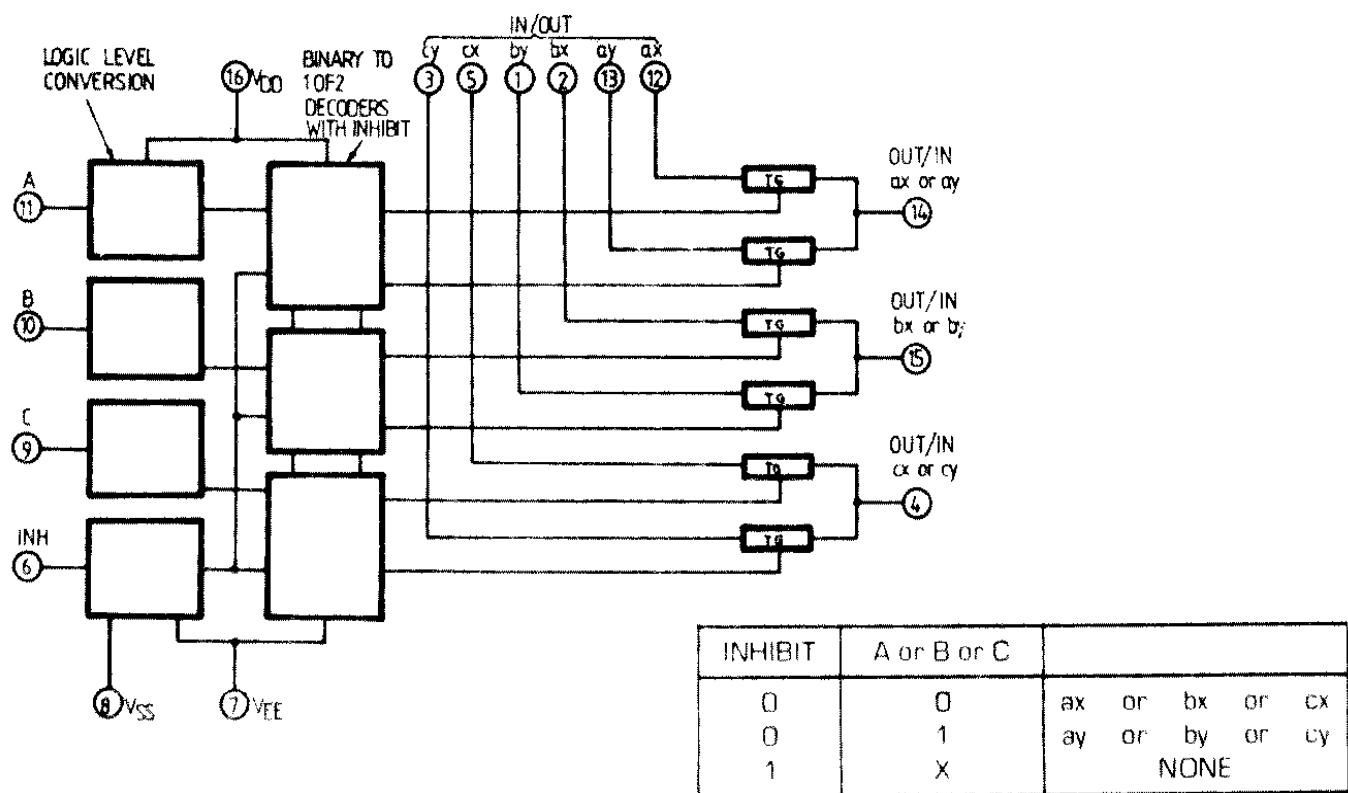
PARAMETER	TEST CONDITIONS						VALUES		UNIT
	V _{EE} (V)	R _L (K)	f _t (KHz)	V _{IS} (V)	V _{SS} (V)	V _{DD} (V)	typ.	max.	
Control (address or inhibit)									
Propagation delay time: Address-to signal OUT channels ON or OFF	0 0 0 - 5			0 0 0 0	5 10 15 5		360 160 120 225	720 320 240 450	ns
Propagation delay time: Inhibit to signal OUT (channel turning ON)	0 0 0 - 10	10		0 0 0 0	5 10 15 5		360 160 120 200	720 320 240 400	ns
Propagation delay time: Inhibit to signal OUT (channel turning OFF)	0 0 0 - 10	0.3			5 10 15 5		200 90 70 130	450 210 160 300	ns
Address or inhibit to signal crosstalk	0	10%			0	10	V _C = V _{DD} - V _{SS} (Square wave)	65	mV peak

(●) Peak to peak voltage symmetrical about $\frac{V_{DD} - V_{EE}}{2}$

(X) Both ends of channel.

FUNCTIONAL DIAGRAMS AND TRUTH TABLES

INHIBIT	INPUT STATES			„ON“ CHANNEL(S)
	C	B	A	
0	0	0	0	0
0	0	0	1	1
0	0	1	0	2
0	0	1	1	3
0	1	0	0	4
0	1	0	1	5
0	1	1	0	6
0	1	1	1	7
1	X	X	X	NONE

MMC 4051 MMC 4052 MMC 4053**MMC 4053****SPECIAL CONSIDERATIONS**

Control of analog signals up to 20 V peak-to-peak can be achieved by digital signal amplitudes of 4.5 to 20 V if $V_{DD} - V_{EE} = 3$ V; a $V_{DD} - V_{EE}$ of up to 13 V can be controlled, for $V_{DD} - V_{EE}$ level differences above 13 V, a $V_{DD} - V_{EE}$ of at least 4.5V is required. For example, if $V_{DD} = +5$ V, $V_{SS} = 0$, and $V_{EE} = -13.5$ V, analog signals from -13.5 V to +4.5 V can be controlled by digital inputs of 0 to 4.5 V. In certain applications, the external load resistor current may include both V_{DD} and signal-line components. To avoid drawing V_{DD} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8 volt. No V_{DD} current will flow through R_1 if the switch current flows into lead 3 on the MMC 4051; leads 3 and 13 on the MMC 4052; leads 4, 14, 15 on the MMC 4053.